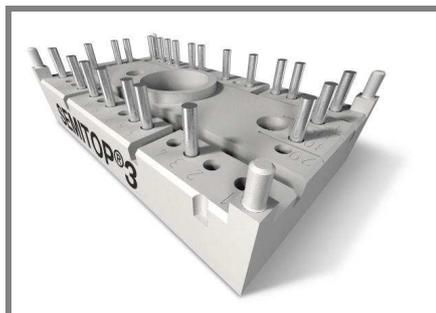


# SK50GB12T4T



SEMITOP® 3

## IGBT Module

SK50GB12T4T

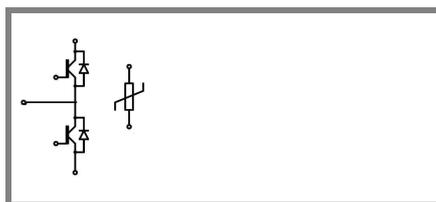
### Features

- One screw mounting module
- Trench4 IGBT technology
- CAL4 technology FWD
- Integrated NTC temperature sensor

### Typical Applications\*

### Remarks

- $V_{CE,sat}$ ,  $V_F$  = chip level value

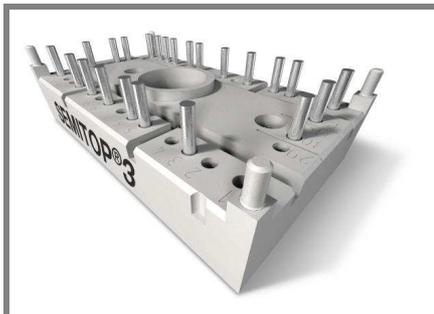


GB-T

Absolute Maximum Ratings		$T_s = 25\text{ °C}$ , unless otherwise specified		
Symbol	Conditions	Values		Units
<b>IGBT</b>				
$V_{CES}$	$T_j = 25\text{ °C}$	1200		V
$I_C$	$T_j = 175\text{ °C}$	$T_s = 25\text{ °C}$	71	A
		$T_s = 70\text{ °C}$	56	A
$I_{CRM}$	$I_{CRM} = 3 \times I_{Cnom}$	150		A
$V_{GES}$		± 20		V
$t_{psc}$	$V_{CC} = 800\text{ V}$ ; $V_{GE} \leq 15\text{ V}$ ; $T_j = 150\text{ °C}$ $V_{CES} < 1200\text{ V}$	10		µs
<b>Inverse Diode</b>				
$I_F$	$T_j = 175\text{ °C}$	$T_s = 25\text{ °C}$	50	A
		$T_s = 70\text{ °C}$	40	A
$I_{FRM}$	$I_{FRM} = 3 \times I_{Fnom}$	150		A
$I_{FSM}$	$t_p = 10\text{ ms}$ ; half sine wave $T_j = 150\text{ °C}$	265		A
<b>Module</b>				
$I_{t(RMS)}$				A
$T_{vj}$		-40 ... +175		°C
$T_{stg}$		-40 ... +125		°C
$V_{isol}$	AC, 1 min.	2500		V

Characteristics		$T_s = 25\text{ °C}$ , unless otherwise specified				
Symbol	Conditions	min.	typ.	max.	Units	
<b>IGBT</b>						
$V_{GE(th)}$	$V_{GE} = V_{CE}$ , $I_C = 1,7\text{ mA}$	5	5,8	6,5	V	
$I_{CES}$	$V_{GE} = 0\text{ V}$ , $V_{CE} = V_{CES}$	$T_j = 25\text{ °C}$			1,0	mA
		$T_j = 125\text{ °C}$				mA
$I_{GES}$	$V_{CE} = 0\text{ V}$ , $V_{GE} = 20\text{ V}$	$T_j = 25\text{ °C}$			600	nA
		$T_j = 125\text{ °C}$				nA
$V_{CE0}$		$T_j = 25\text{ °C}$	1,1	1,3	V	
		$T_j = 150\text{ °C}$	1	1,2	V	
$r_{CE}$	$V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}$	15		mΩ	
		$T_j = 150\text{ °C}$	25		mΩ	
$V_{CE(sat)}$	$I_{Cnom} = 50\text{ A}$ , $V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}_{chiplev.}$	1,85	2,05	V	
		$T_j = 150\text{ °C}_{chiplev.}$	2,25	2,45	V	
$C_{ies}$	$V_{CE} = 25$ , $V_{GE} = 0\text{ V}$			2,77	nF	
$C_{oes}$				0,2	nF	
$C_{res}$				0,16	nF	
$Q_G$	$V_{GE} = -7V...+15V$			375	nC	
$R_{Gint}$	$T_j = 25\text{ °C}$			4	Ω	
$t_{d(on)}$	$R_{Gon} = 32\text{ Ω}$ $di/dt = 920\text{ A/µs}$	$V_{CC} = 600V$ $I_C = 50A$			63	ns
$t_r$					65	ns
$E_{on}$					8,3	mJ
$t_{d(off)}$	$R_{Goff} = 32\text{ Ω}$ $di/dt = 920\text{ A/µs}$	$T_j = 150\text{ °C}$			521	ns
			$V_{GE} = \pm 15\text{ V}$			80
$E_{off}$					5	mJ
$R_{th(j-s)}$	per IGBT			0,9	K/W	

# SK50GB12T4T



**SEMITOP<sup>®</sup> 3**

## IGBT Module

**SK50GB12T4T**

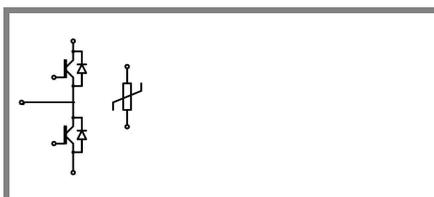
### Features

- One screw mounting module
- Trench4 IGBT technology
- CAL4 technology FWD
- Integrated NTC temperature sensor

### Typical Applications\*

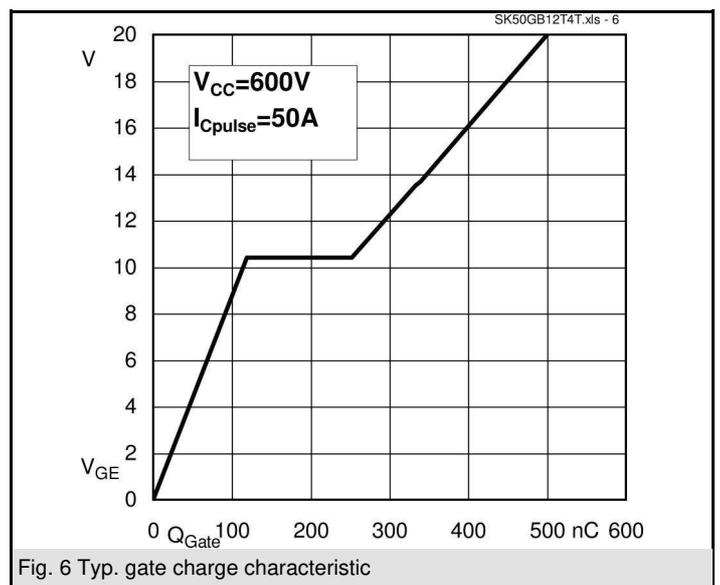
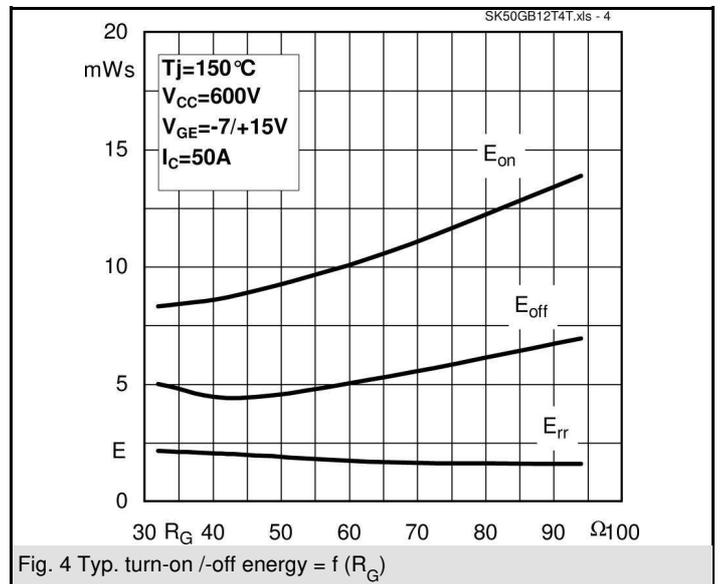
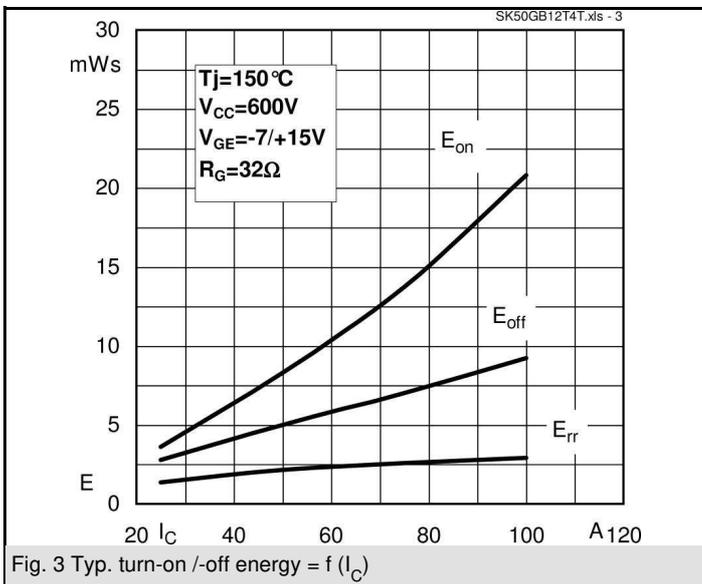
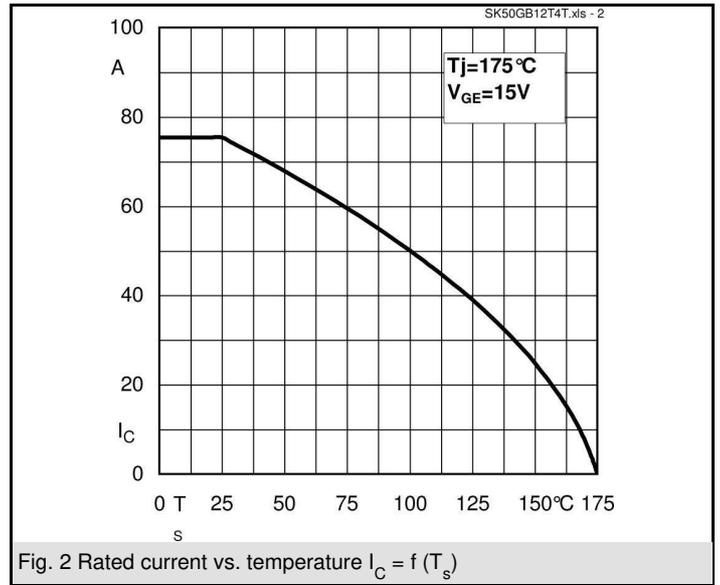
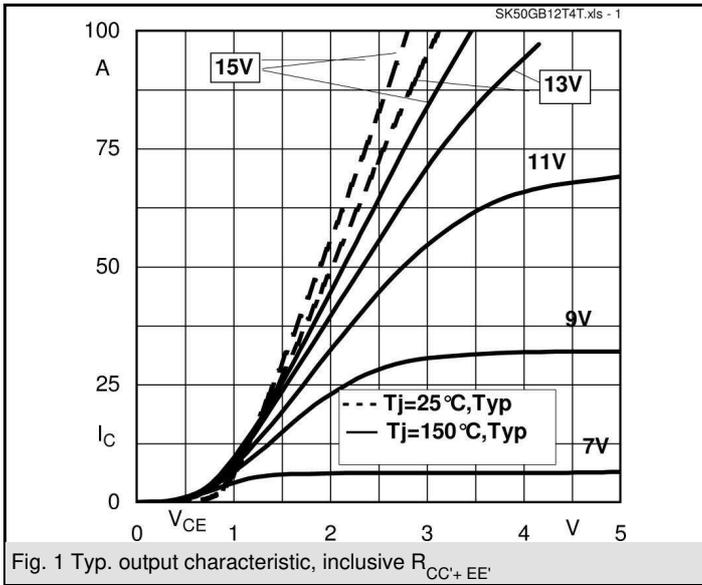
### Remarks

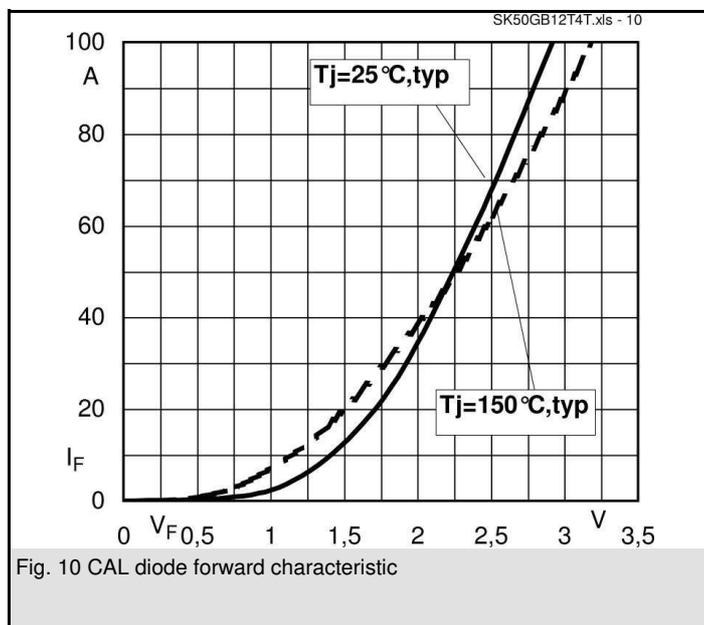
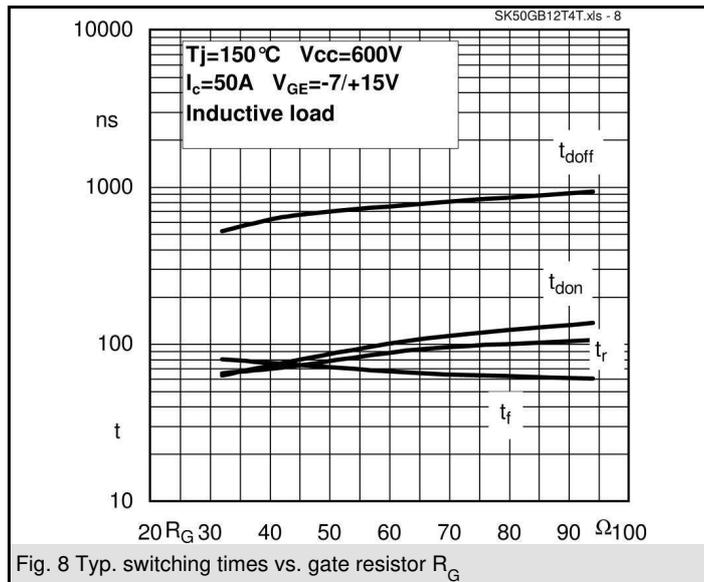
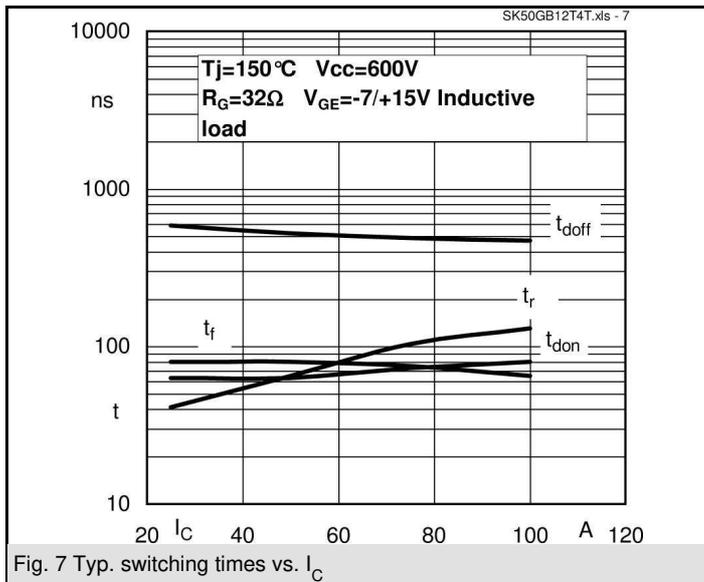
- $V_{CE,sat}$ ,  $V_F$  = chip level value

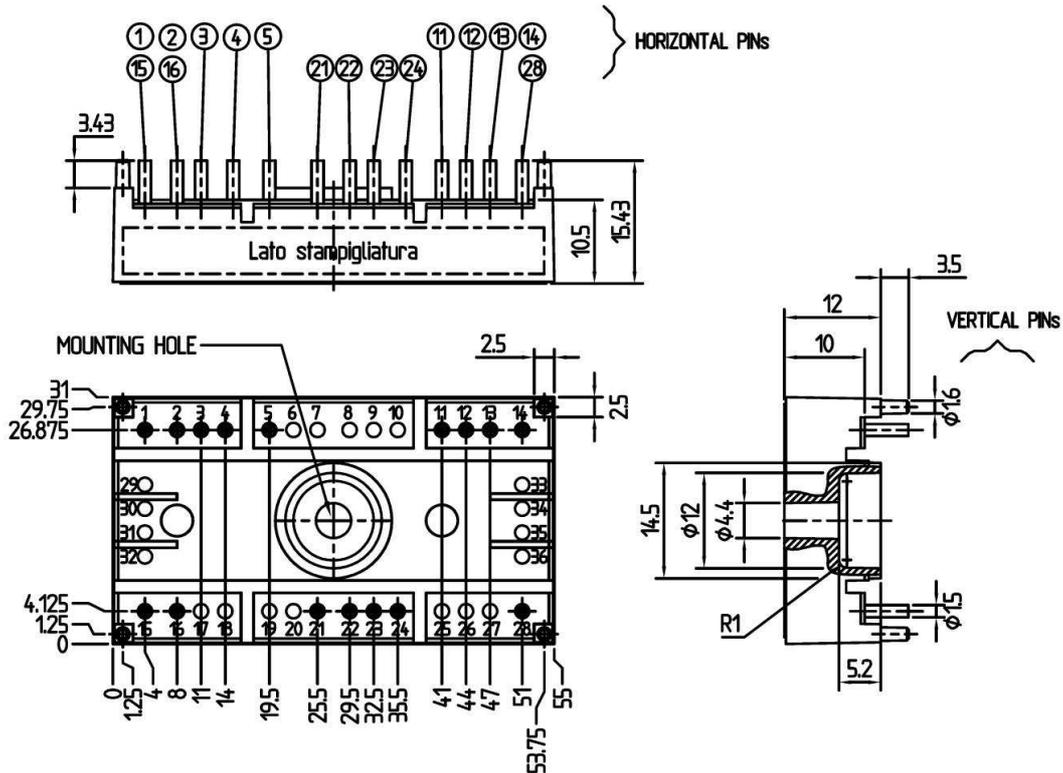


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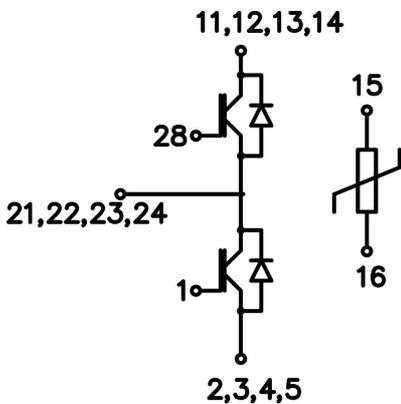
Characteristics			min.	typ.	max.	Units
<b>Symbol</b>	<b>Conditions</b>					
<b>Inverse Diode</b>						
$V_F = V_{EC}$	$I_{Fnom} = 50 \text{ A}; V_{GE} = 0 \text{ V}$	$T_j = 25 \text{ }^\circ\text{C}_{\text{chiplev.}}$		2,2	2,55	V
		$T_j = 150 \text{ }^\circ\text{C}_{\text{chiplev.}}$		2,18	2,5	V
$V_{F0}$		$T_j = 25 \text{ }^\circ\text{C}$		1,3	1,5	V
		$T_j = 150 \text{ }^\circ\text{C}$		0,9	1,1	V
$r_F$		$T_j = 25 \text{ }^\circ\text{C}$		19	21	m $\Omega$
		$T_j = 150 \text{ }^\circ\text{C}$		26	28	m $\Omega$
$I_{RRM}$	$I_F = 50 \text{ A}$	$T_j = 150 \text{ }^\circ\text{C}$		30		A
$Q_{rr}$	$di/dt = 920 \text{ A}/\mu\text{s}$			7,2		$\mu\text{C}$
$E_{rr}$	$V_{CC} = 600\text{V}$			2,15		mJ
$R_{th(j-s)D}$	per diode			1,24		K/W
$M_s$	to heat sink				2,5	Nm
w				30		g
<b>Temperature sensor</b>						
$R_{100}$	$T_s = 100^\circ\text{C}$ ( $R_{25} = 5\text{k}\Omega$ )			493 $\pm$ 5%		$\Omega$







Case T73 (Suggested hole diameter for the solder pins and mounting plastic pins: 2mm)



Case T73

GB-T

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

### \*IMPORTANT INFORMATION AND WARNINGS

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